Dual N-channel MOSFET

Copper plating pads

KFCAB12058NL
Datasheet

For additional information or question, please contact Nuvoton Technology Corporation Japan.

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1. GENERAL DESCRIPTION

Gate resistor installed Dual N-channel MOSFET
for lithium-ion secondary battery protection circuits.

2. FEATURES

- Source-source On-state Resistance: RSS(on) typ = 4.3 mΩ (VGS = 3.8 V)
- CSP (Chip Size Package)
- Copper plating pads for embedded board
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1)

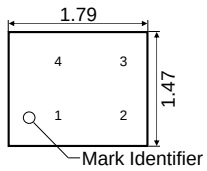
3. MARKING SYMBOL: KD

4. PACKAGING

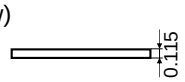
Embossed type (Thermo-compression sealing): 10,000 pcs / reel (standard)

Unit: mm

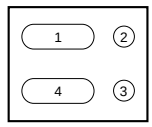
(Top View)



(Front View)



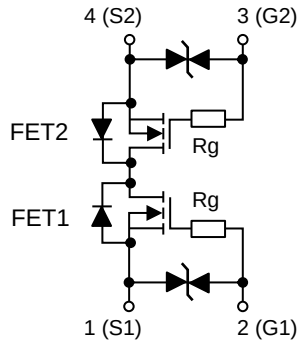
(Bottom View)



1. Source1 (FET1) 2. Gate1 (FET1)
4. Source2 (FET2) 3. Gate2 (FET2)

Package	TCSP1518012-N2

Equivalent Circuit



5. ABSOLUTE MAXIMUM RATINGS Ta = 25 °C

Parameter		Symbol	Rating	Unit
Source-source Voltage		VSS	12	V
Gate-source Voltage		VGS	± 8	V
Source Current	DC *1	IS1	9.3	A
	DC *2	IS2	15.8	
	DC *3	IS3	21.1	
	Pulsed *4	ISp	93	
Total Power Dissipation	DC *1	PD1	0.49	W
	DC *2	PD2	1.40	
	DC *3	PD3	2.50	
Operating Junction and Storage Temperature Range		Tj, Tstg	- 55 to + 150	°C

6. THERMAL CHARACTERISTICS Ta = 25 °C

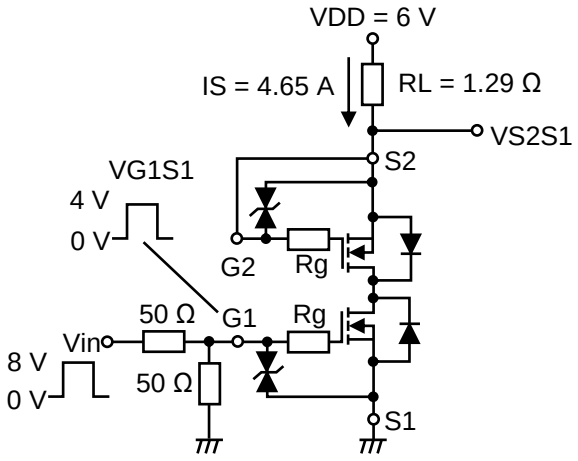
Parameter	Symbol	Rating	Unit
Thermal Resistance (ch-a)	Rth1 *1	255	°C / W
	Rth2 *2	89	
	Rth3 *3	50	

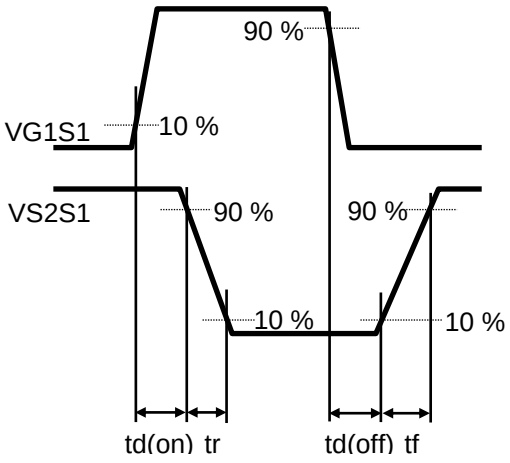
Note *1 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm).
FR4 board partially covered with copper pad (23 mm^2 area, 36 µm thickness).
*2 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm).
FR4 board fully covered with copper pad (604 mm^2 area, 36 µm thickness).
*3 Mounted on ceramic board (70 mm x 70 mm x t1.0 mm).
*4 t = 10 µs, Duty Cycle ≤ 1 %.

7. ELECTRICAL CHARACTERISTICS Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	12			V
Zero Gate Voltage Source Current	ISSS	VSS = 12 V, VGS = 0 V			1	μA
Gate-source Leakage Current	IGSS1	VGS = ± 8 V, VSS = 0 V			± 5	μA
	IGSS2	VGS = ± 5 V, VSS = 0 V			± 0.5	
Gate-source Threshold Voltage	Vth	IS = 0.50 mA, VSS = 6 V	0.35	0.90	1.40	V
Source-source On-state Resistance	RSS(on)1	IS = 4.65 A, VGS = 4.5 V	2.8	4.1	5.4	mΩ
	RSS(on)2	IS = 4.65 A, VGS = 3.8 V	2.9	4.3	5.6	
	RSS(on)3	IS = 4.65 A, VGS = 3.1 V	3.0	4.7	6.9	
	RSS(on)4	IS = 4.65 A, VGS = 2.5 V	3.3	5.6	10.7	
Body Diode Forward Voltage	VF(s-s)	IF = 4.65 A, VGS = 0 V		0.7	1.0	V
Input Capacitance *1	Ciss	VSS = 10 V, VGS = 0 V, f = 1 kHz		3500		pF
Output Capacitance *1	Coss			520		
Reverse Transfer Capacitance *1	Crss			450		
Turn-on Delay Time *1, *2	td(on)	VDD = 6 V, VGS = 0 to 4 V		1.1		μs
Rise Time *1, *2	tr	IS = 4.65 A		1.9		
Turn-off Delay Time *1, *2	td(off)	VDD = 6 V, VGS = 4 to 0 V		4.8		μs
Fall Time *1, *2	tf	IS = 4.65 A		3.0		
Total Gate Charge *1	Qg	VDD = 6 V		29		nC
Gate-source Charge *1	Qgs	VGS = 0 to 4 V		7.9		
Gate-drain Charge *1	Qgd	IS = 9.3 A		5.4		
Gate Resistance *1	Rg	f = 1 MHz	400	700	1000	Ω

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.
All electrical characteristics are measured values in the surface mount state.
*1 Guaranteed by design, not subject to production testing.
*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time.

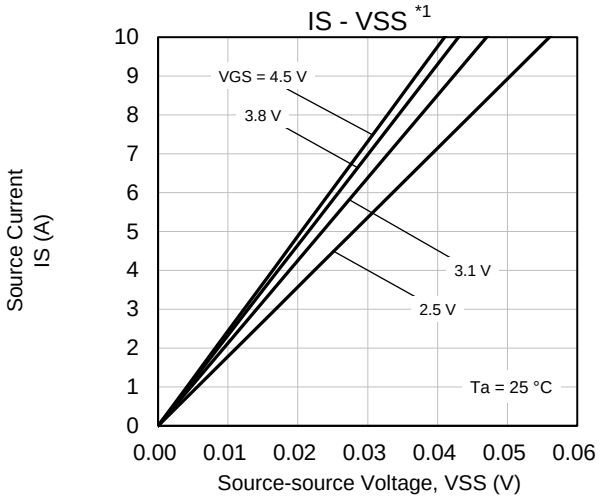


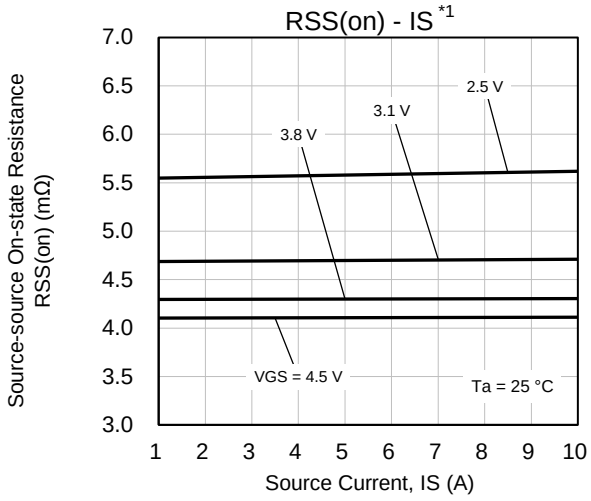


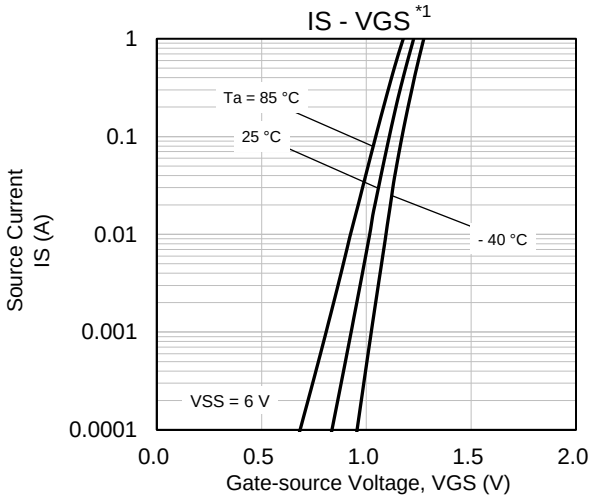
8. ELECTROSTATIC DISCHARGE CHARACTERISTIC Ta = 25 °C ± 3 °C

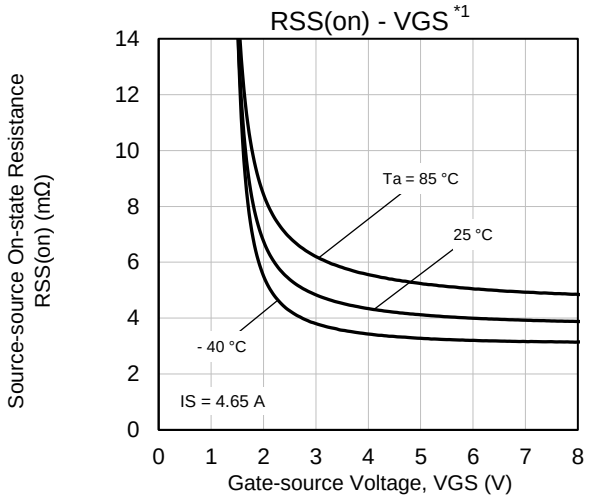
Standard	Test Type	Symbol	Conditions	Class	Value	Unit
AEC-Q101-001	Human Body Model	HBM	C = 100 pF, R = 1.5 kΩ	H2	> 2k to ≤ 4k	V

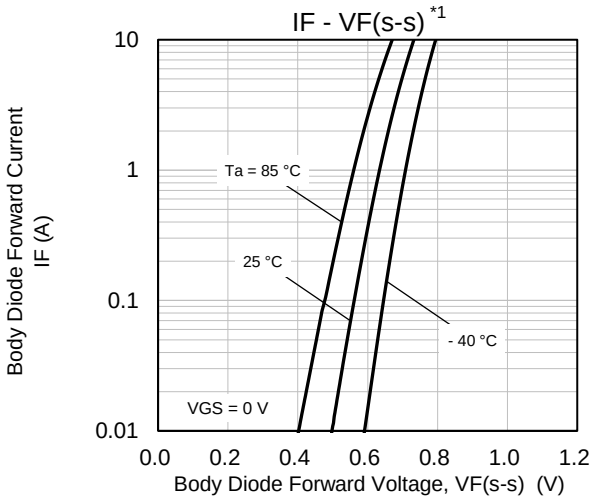
9. TECHNICAL DATA (Reference)

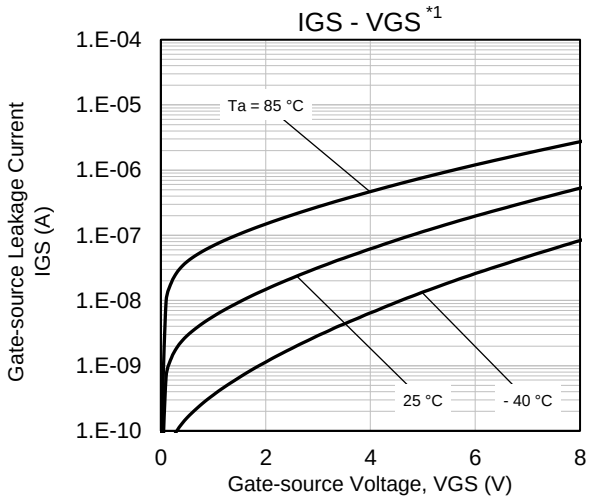












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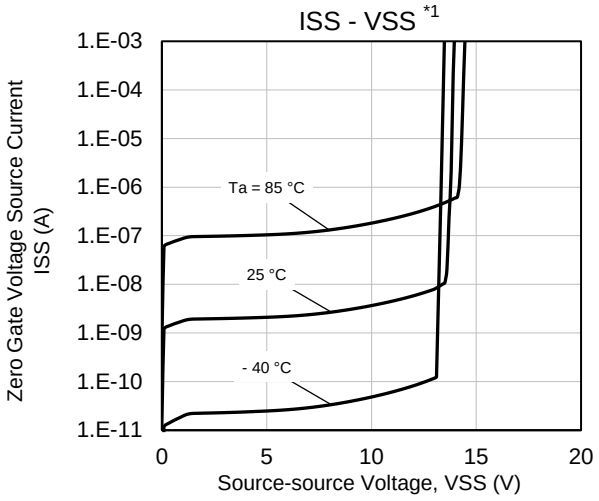
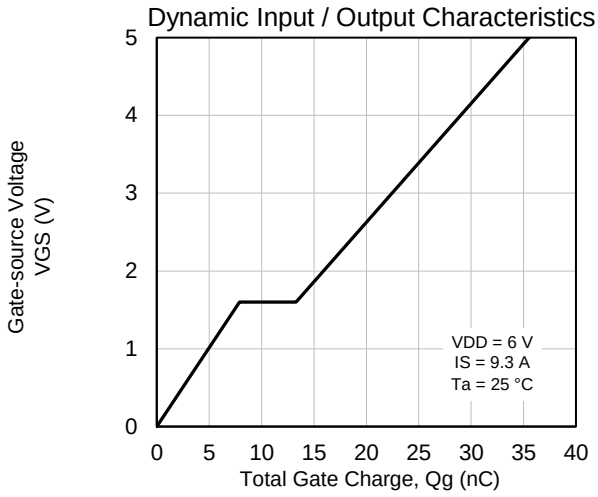
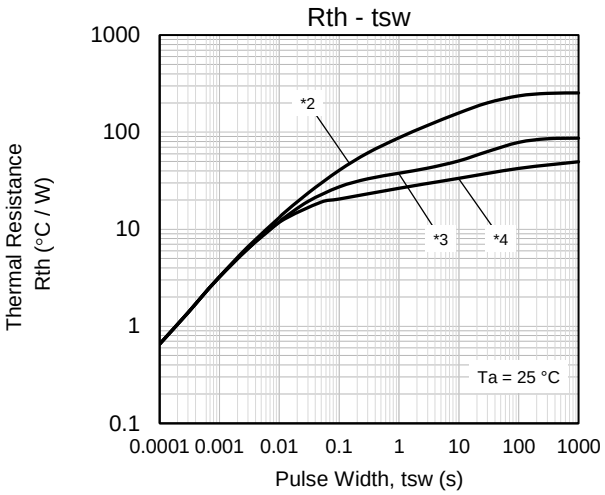
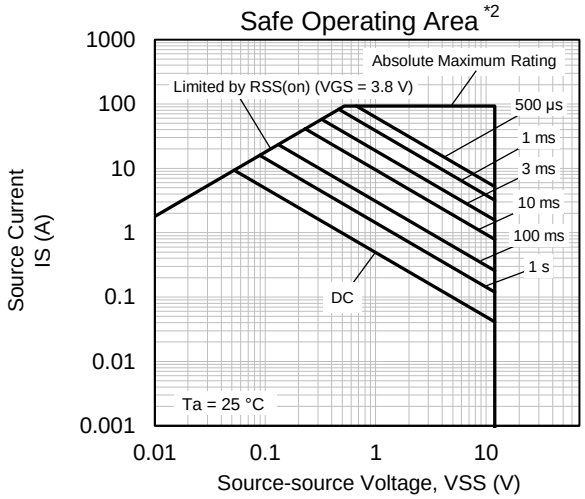
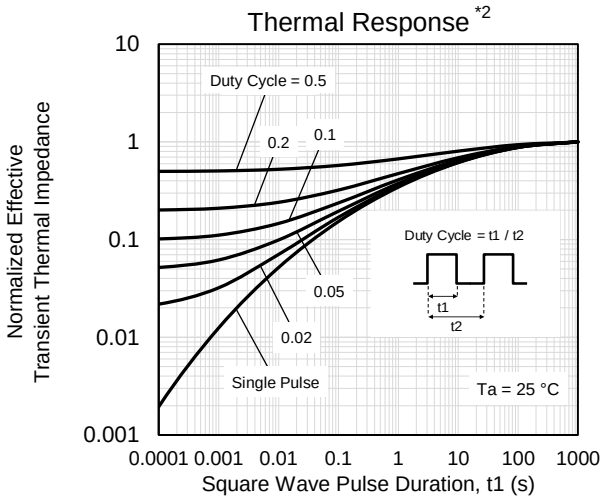










Note

Technical data are measured values in the surface mount state.

*1 Pulse measurement.

*2 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm).
FR4 board partially covered with copper pad
(23 mm² area, 36 µm thickness).

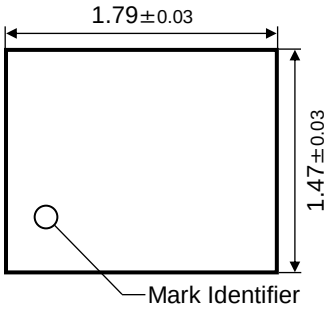
*3 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm).
FR4 board fully covered with copper pad
(604 mm² area, 36 µm thickness).

*4 Mounted on ceramic board (70 mm x 70 mm x t1.0 mm).

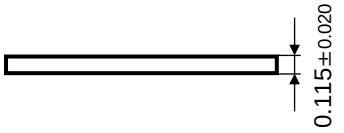
10. OUTLINE

(Top View)

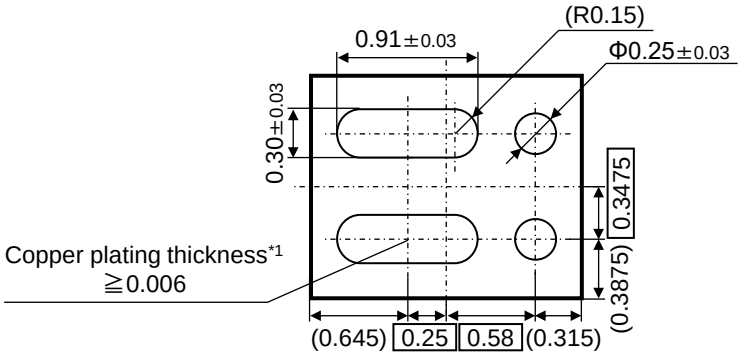
Unit: mm



(Front View)



(Bottom View)



Note *1 Copper plating thickness guaranteed by sampling test.

11. REVISION HISTORY

Date	Revision	Description
2024.4.15	1.00	1. Initially issued.
2025.1.9	2.00	1. Changed special attention and precautions notes.

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